TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74ACT112FN

#### Dual J-K Flip Flop with Preset and Clear

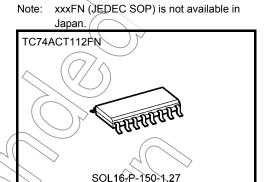
The TC74ACT112 is an advanced high speed CMOS DUAL J-K FLIP FLOP fabricated with silicon gate and double-layer metal wiring  $C^2MOS$  technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

In accordance with the logic level given J and K input this device changes state on negative going transition of the clock pulse.  $\overline{\text{CLEAR}}$  and  $\overline{\text{PRESET}}$  are independent of the clock and accomplished by a low logic level on the corresponding input.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

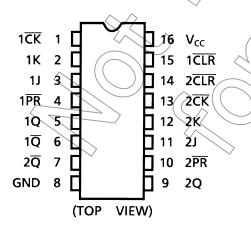


Weight SOL16-P-150-1.27 0.13 g (typ.)

#### **Features**

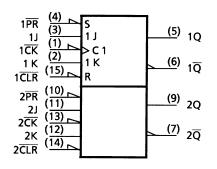
- High speed:  $f_{max} = 175 \text{ MHz}$  (typ.) at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 4 \mu A \text{ (max)}$  at  $T_{CC} = 25 \text{°C}$
- Compatible with TTL outputs:  $V_{IL} = 0.8 \text{ V (max)}$   $V_{IH} = 2.0 \text{ V (min)}$
- Symmetrical output impedance: |IOH| = IOL = 24 mA (min) Capability of driving 50  $\Omega$  transmission lines.
- Balanced propagation delays: tpLH ~ tpHL
- Pin and function compatible with 74F112

### **Pin Assignment**



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# **IEC Logic Symbol**

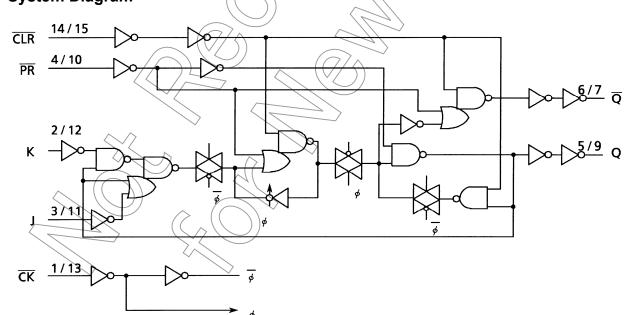


### **Truth Table**

		Inputs	Out	puts	Function		
CLR	PR	J	K	CK	Q	Q	Tunction
L	Н	Х	Х	Х	L	Н	Clear
Н	L	Х	Х	Х	Н	L	Preset
L	L	Х	Х	Х	Н	Н	
Н	Н	L	L	$\neg$	Qn	$\overline{Q}_n$	No Change
Н	Η	Ш	Η	$\rightarrow$	L	Η	
Н	Н	Н	L	$\neg$	Н	L	
Н	Н	Н	Н	$\Box$	$\overline{Q}_n$	Qn	Toggle
Н	Н	Х	Х		Qn	$\overline{Q}_n$	No Change

X: Don't care

# System Diagram



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#### **Absolute Maximum Ratings (Note 1)**

Characteristics	Symbol	Symbol Rating	
Supply voltage range	V <sub>CC</sub>	−0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	< ∨
Input diode current	I <sub>IK</sub>	±20	mA
Output diode current	lok	±50	mA
DC output current	lout	±50	mA
DC V <sub>CC</sub> /ground current	Icc	±100	mA
Power dissipation	PD	180	mW
Storage temperature	T <sub>stg</sub>	-65 to 150	<sup>→</sup> °C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Operating Ranges (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	Vec	4.5 to 5.5	٧
Input voltage	((VIN	0 to V <sub>CC</sub>	V
Output voltage	Vout	O to VCC	V
Operating temperature	// T <sub>opr</sub>	-40 to 85	°C
Input rise and fall time	dt/dV _	( ) \ 0 to 10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.



#### **Electrical Characteristics**

#### **DC Characteristics**

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40 to 85°C		Unit	
Characteristics	Зупівої				V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic
High-level input voltage	V <sub>IH</sub>	_			4.5 to 5.5	2.0	_	$\mathcal{M}$	2.0	_	٧
Low-level input voltage	V <sub>IL</sub>	_			4.5 to 5.5	_	(	0.8	)}_	0.8	٧
	V <sub>OH</sub>	V <sub>IN</sub>	$I_{OH} = -50 \mu A$		4.5	4.4	4.5	/A	4.4	_	V
High-level output voltage		= V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -24 mA		4.5	3.94	<u>\</u> _\`	<i>)</i>	3.80 —	_	
3.33			$I_{OH} = -75 \text{ mA}$	(Note)	5.5	-((	7/	, —	3.85	_	
	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OL} = 50 \mu A$		4.5		0.0	0.1	1	0.1	
Low-level output voltage			$I_{OL} = 24 \text{ mA}$		4.5		<u>\</u>	0.36	(F)	0.44	V
3			$I_{OL} = 75 \text{ mA}$	(Note)	5.5	1		- (		1.65	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND			5(5)	<u></u>	-\cap \	±0(1		±1.0	μА
Quiescent supply current	Icc	$V_{IN} = V_{C}$	<sub>C</sub> or GND	5.5	_	_	4.0	4	40.0	μА	
	Ic	-	: V <sub>IN</sub> = 3.4 V out: V <sub>CC</sub> or GND		5.5	_	-((	1.35		1.5	mA

Note: This spec indicates the capability of driving 50  $\Omega$  transmission lines. One output should be tested at a time for a 10 ms maximum duration.

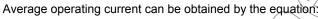
# Timing Requirements (input: $t_r = t_f = 3 \text{ ns}$ )

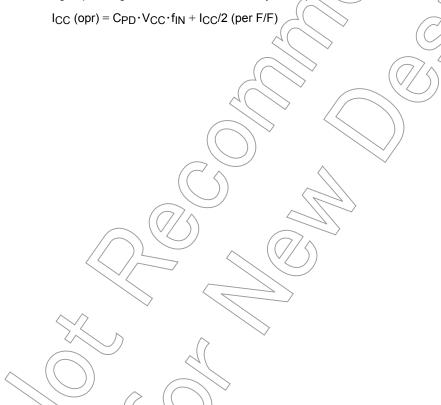
Characteristics	Symbol	Test Condition		Ta = 25°C	Ta = −40 to 85°C	Unit
			V <sub>CC</sub> (V)	Limit	Limit	
Minimum pulse width (CK)	(***(L))		5.0 ± 0.5	5.0	5.0	ns
Minimum pulse width	*tw-(H)	$\sim (0/\hat{\gamma})$				
(CLR, PR)	ŧW (L)		$5.0 \pm 0.5$	5.0	5.0	ns
Minimum set-up time	) t <sub>s</sub>		$5.0 \pm 0.5$	5.0	5.0	ns
Minimum hold time	t <sub>h</sub>	_	$5.0 \pm 0.5$	1.0	1.0	ns
Minimum removal time (CLR, PR)	t <sub>rem</sub>	_	5.0 ± 0.5	3.0	3.0	ns

AC Characteristics (CL = 50 pF, RL = 500  $\Omega$ , input:  $t_r$  =  $t_f$  = 3 ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
	- <b>,</b>		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	
Propagation delay time ( $\overline{\text{CK}}$ -Q, $\overline{\text{Q}}$ )	t <sub>pLH</sub> t <sub>pHL</sub>	_	5.0 ± 0.5	_	6.4	10.0	1.0	11.5	ns
Propagation delay time (CLR, PR-Q, Q)	t <sub>pLH</sub>	_	5.0 ± 0.5	_	6.8	10.5	0.t	12.0	ns
Maximum clock frequency	f <sub>max</sub>	_	5.0 ± 0.5	85	100/	$\langle \rangle$	85	_	MHz
Input capacitance	C <sub>IN</sub>	_		-(	5	10	_	10	pF
Power dissipation capacitance	C <sub>PD</sub> (Note)	_			32	_		_	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

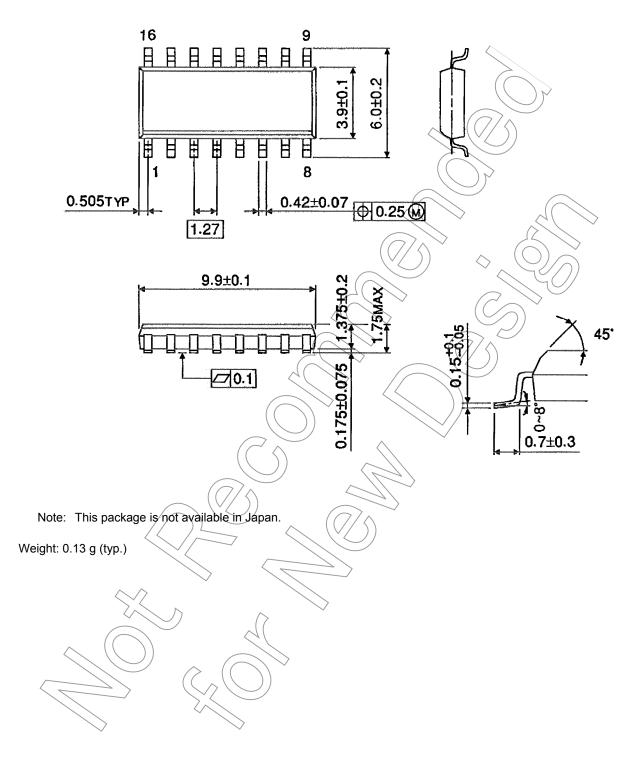




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# **Package Dimensions (Note)**

SOL16-P-150-1.27 Unit: mm



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